





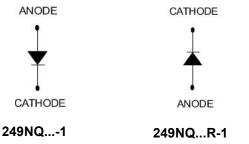
249NQ135/R-1 249NQ135/R-1 SCHOTTKY RECTIFIER



Features

- 175℃ T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5' S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

The top side is terminal, the bottom side is base plate.

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage	V _{RRM}	-	135	249NQ135/R-1	\ /
Working Peak Reverse Voltage DC Blocking Voltage	$V_{RWM} \ V_{R}$		150	249NQ150/R-1	V
Average Forward Current	I _{F(AV)}	50% duty cycle @Tc=117°C, rectangular wave form	240		Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	2760		Α

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	\/	@ 240A, Pulse, T _J = 25 °C	0.85	1.07	V
	V _{F1}	@ 480A, Pulse, T _J = 25 °C	0.96	1.27	\ \ \
	\/	@ 240A, Pulse, T _J = 125 °C	0.74	0.80	V
	V_{F2}	@ 480A, Pulse, T _J = 125 °C	0.81	0.86	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.08	6	mA
	I_{R2}	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	4.5	85	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	3990	6000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^{^{\}star}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specific	cation	Units
Junction Temperature	TJ	-	-55 to	+175	°C
Storage Temperature	T _{stg}	-	-55 to	+175	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.2	5	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.0	7	°C/W
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque Terminal Torque	23(min) 29(max) 35(min) 46(max)	Kg-cm
Approximate Weight	wt	-	36		g
Case Style		PRM1-1			

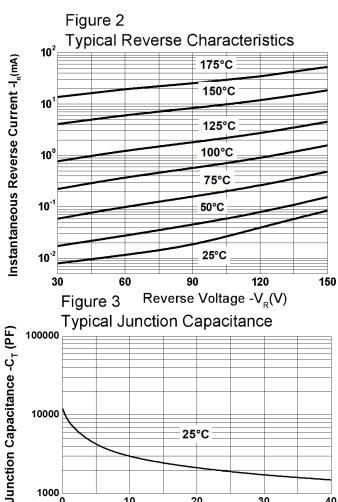






Ratings and Characteristics Curves

Figure1 **Typical Forward Characteristics** Instantaneous Forward Current -I_F(A) 175°C 10² 125°C 25°C 10¹ 10_{0.1} 0.3 0.5 0.7 0.9 1.1 Forward Voltage -V_E(V)

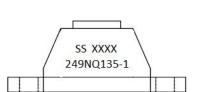


Ordering Information

Device	Package	Shipping
249NQ SERIES	PRM1-1(Pb-Free)	27pcs/ box

Marking Diagram

1000



Where XXXX is YYWW

40

1st row SS YYWW 2nd row 249NQ135-1 SS = SS = Year = Week

Reverse Voltage -V_R(V)

Cautions: Molding resin Epoxy resin UL:94V-0

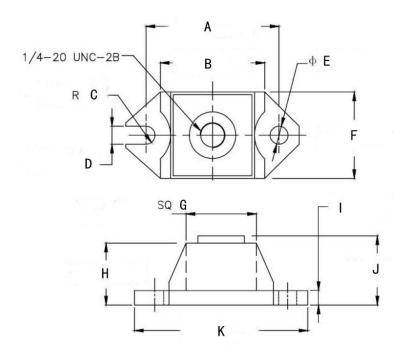
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Mechanical Dimensions PRM1-1 (Inches/Millimeters)



	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	29.35	30.95	1.155	1.219	
В	24.77	26.04	0.975	1.026	
С	1.79	2.19	0.070	0.087	
D	3.73	4.24	0.146	0.167	
E	3.73	4.24	0.146	0.167	
F	18.42	19.69	0.725	0.775	
G	18.55	19.55	0.730	0.770	
Н	13.59	14.47	0.535	70.500	
I	3.05	3.90	0.120	0.154	
J	14.87	15.87	0.585	0.625	
K	38.61	39.62	1.520	1.560	







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